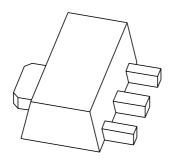
DISCRETE SEMICONDUCTORS

DATA SHEET



PXT3906 PNP switching transistor

Product specification Supersedes data of 1999 Apr 14 2004 Nov 22





Philips Semiconductors

PNP switching transistor

PXT3906

FEATURES

- Low current (max. 100 mA)
- Low voltage (max. 40 V).

APPLICATIONS

• High-speed saturated switching applications.

DESCRIPTION

PNP switching transistor in a SOT89 plastic package. NPN complement: PXT3904.

MARKING

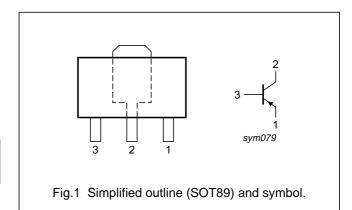
TYPE NUMBER	MARKING CODE(1)		
PXT3906	*2A		

Note

- 1. * = p: Made in Hong Kong.
 - * = t: Made in Malaysia.
 - * = W: Made in China.

PINNING

PIN	DESCRIPTION	
1	emitter	
2	collector	
3	base	



ORDERING INFORMATION

TYPE NUMBER	PACKAGE			
TIPE NOMBER	NAME DESCRIPTION \			
PXT3906	SC-62 plastic surface mounted package; collector pad for good heat transfer; 3 leads		SOT89	

PNP switching transistor

PXT3906

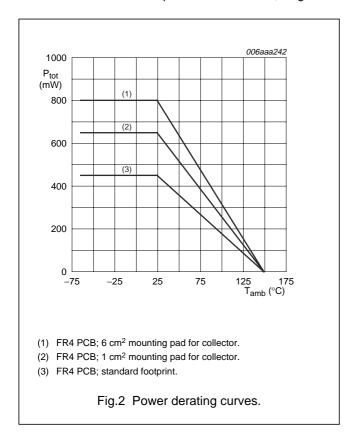
LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	-40	V
V _{CEO}	collector-emitter voltage	open base	_	-40	V
V _{EBO}	emitter-base voltage	open collector	_	-6	V
I _C	collector current (DC)		_	-100	mA
I _{CM}	peak collector current		_	-200	mA
I _{BM}	peak base current		_	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C			
		note 1	_	0.45	W
		note 2	_	0.65	W
		note 3	_	0.8	W
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	ambient temperature		-65	+150	°C

Notes

- 1. Device mounted on a printed-circuit board, single-sided copper, tin-plated and standard footprint.
- 2. Device mounted on a printed-circuit board, single-sided copper, tin-plated and mounting pad for collector 1 cm².
- 3. Device mounted on a printed-circuit board, single-sided copper, tin-plated and mounting pad for collector 6 cm².



PNP switching transistor

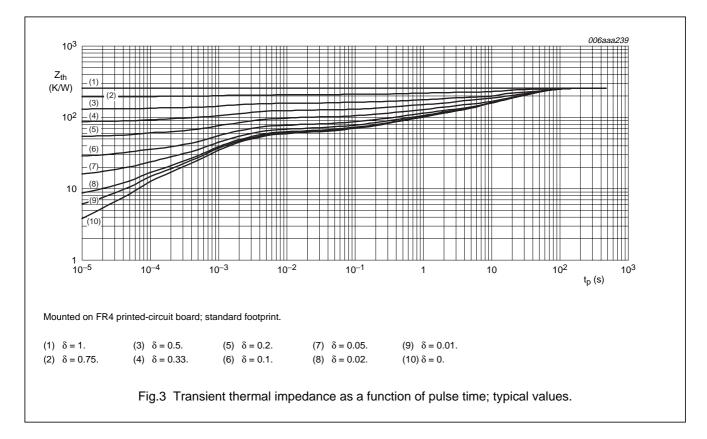
PXT3906

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to	in free air		
	ambient	note 1	278	K/W
		note 2	192	K/W
		note 3	156	K/W
R _{th(j-s)}	thermal resistance from junction to soldering point		80	K/W

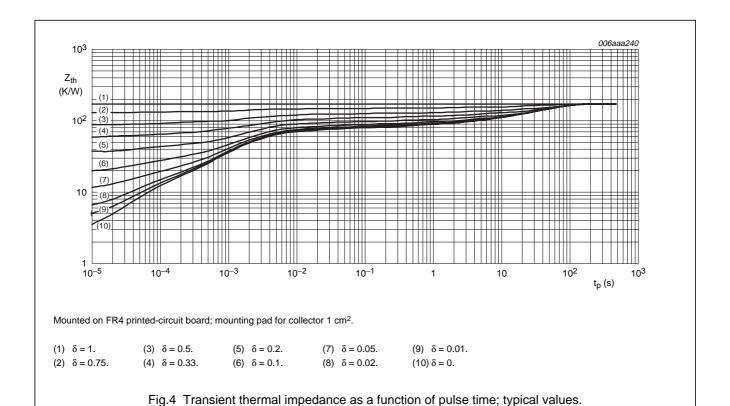
Notes

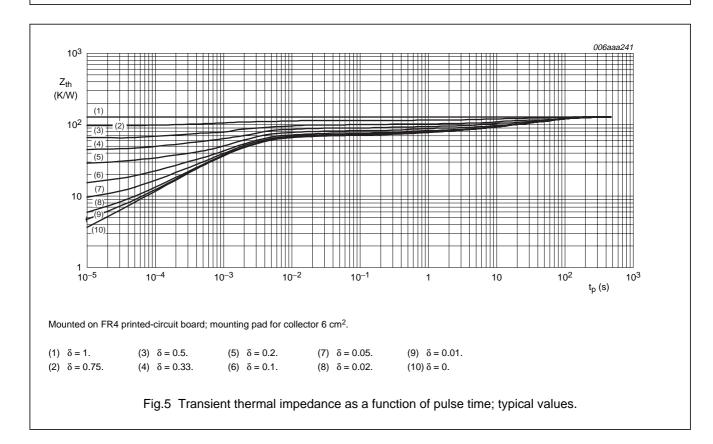
- 1. Device mounted on a printed-circuit board, single-sided copper, tin-plated and standard footprint.
- 2. Device mounted on a printed-circuit board, single-sided copper, tin-plated and mounting pad for collector 1 cm².
- 3. Device mounted on a printed-circuit board, single-sided copper, tin-plated and mounting pad for collector 6 cm².



PNP switching transistor

PXT3906





PNP switching transistor

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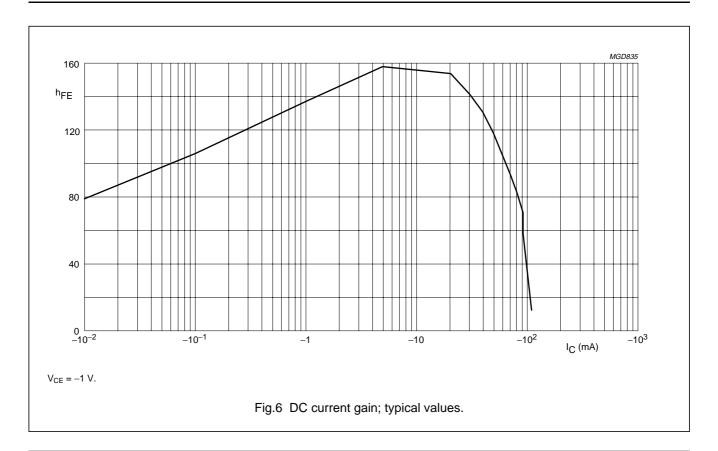
CHARACTERISTICS

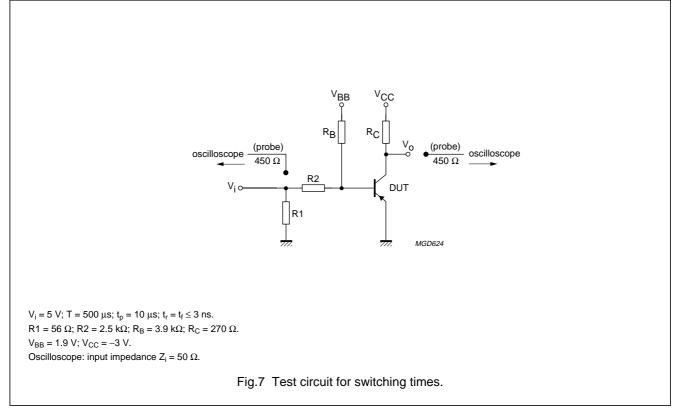
 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$I_E = 0 \text{ A}; V_{CB} = -30 \text{ V}$	_	-50	nA
I _{EBO}	emitter-base cut-off current	I _C = 0 A; V _{EB} = -6 V	_	-50	nA
h _{FE}	DC current gain	V _{CE} = −1 V; (see Fig.6)			
		$I_{C} = -0.1 \text{ mA}$	60	-	
		$I_C = -1 \text{ mA}$	80	_	
		$I_C = -10 \text{ mA}$	100	300	
		$I_C = -50 \text{ mA}$	60	_	
		$I_{C} = -100 \text{ mA}$	30	_	
V _{CEsat}	collector-emitter saturation	$I_C = -10 \text{ mA}; I_B = -1 \text{ mA}$	_	-250	mV
	voltage	$I_C = -50 \text{ mA}; I_B = -5 \text{ mA}$	_	-400	mV
V _{BEsat}	base-emitter saturation voltage	$I_C = -10 \text{ mA}; I_B = -1 \text{ mA}$	-650	-850	mV
		$I_C = -50 \text{ mA}; I_B = -5 \text{ mA}$	_	-950	mV
C _c	collector capacitance	$I_E = i_e = 0 \text{ A}; V_{CB} = -5 \text{ V}; f = 1 \text{ MHz}$	_	4.5	pF
C _e	emitter capacitance	$I_C = i_C = 0 \text{ A}; V_{EB} = -500 \text{ mV}; f = 1 \text{ MHz}$	_	10	pF
f _T	transition frequency	$I_C = -10 \text{ mA}; V_{CE} = -20 \text{ V}; f = 100 \text{ MHz}$	250	_	MHz
F	noise figure	I_C = -100 μA; V_{CE} = -5 V; R_S = 1 kΩ; f = 10 Hz to 15.7 kHz	_	4	dB
Switching t	imes (between 10% and 90% lev	rels); (see Fig.7)		•	
t _{on}	turn-on time	$I_{Con} = -10 \text{ mA}; I_{Bon} = -1 \text{ mA};$	_	65	ns
t _d	delay time	I _{Boff} = 1 mA	_	35	ns
t _r	rise time	1	_	35	ns
t _{off}	turn-off time	1	_	300	ns
t _s	storage time	1	_	225	ns
t _f	fall time	1	_	75	ns

PNP switching transistor

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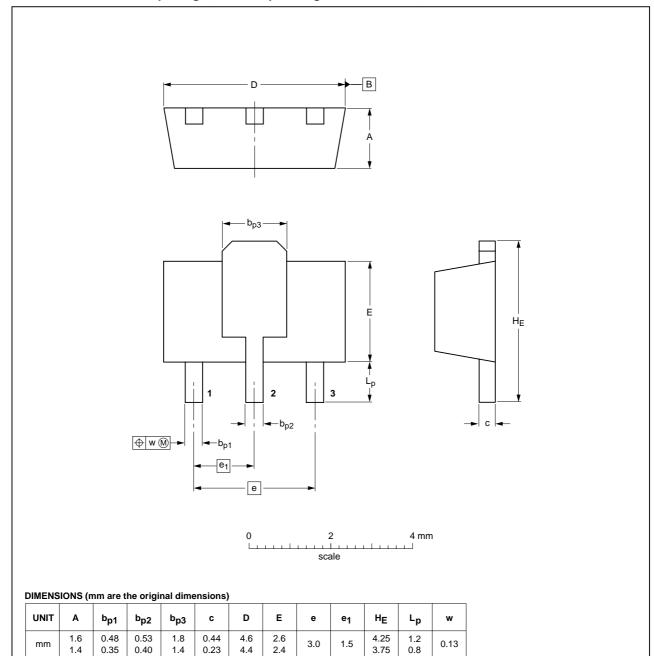
PNP switching transistor

PXT3906

PACKAGE OUTLINE

Plastic surface mounted package; collector pad for good heat transfer; 3 leads

SOT89



OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT89		TO-243	SC-62			99-09-13 04-08-03

PNP switching transistor

PXT3906

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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Notes

- Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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